



Neural Networks

CS 479



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Preface

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Note that the course currently is CS 489, but in winter 2022, this course will become CS 479.

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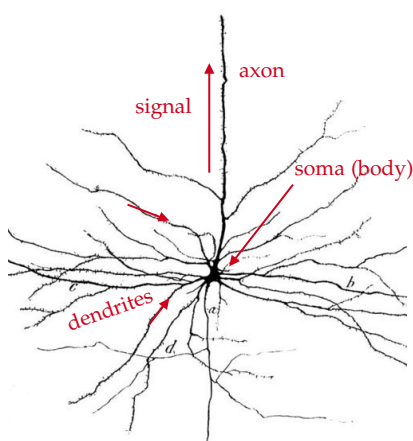
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Neuron Models

1.1 Neurons

A neuron is a special cell that can send and receive signals from other neurons.

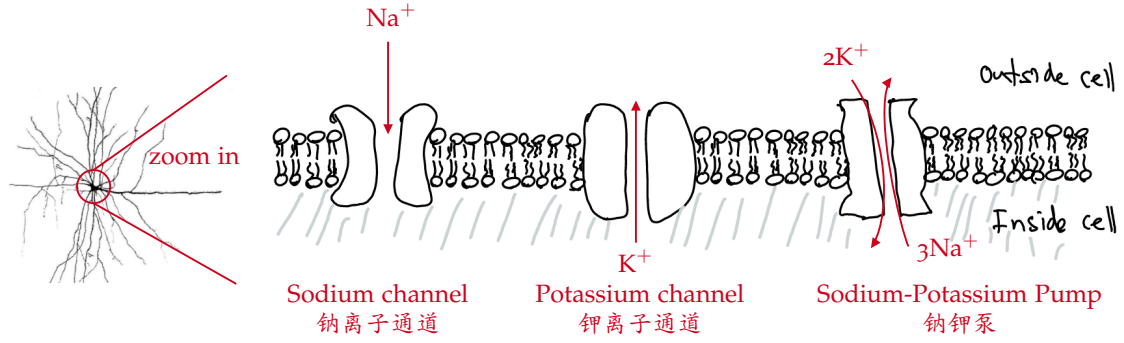
A neuron can be quite long, sending its signal over a long distance; up to **50m long!** But most are much shorter.



- Soma: 体细胞.
- Axon: 轴突. The electrical signal generated by soma travels along the axon.
- Dendrites: 树突. The electrical excitation is collected in the dendrites.
- Synapse: 突触. Structure that permits a neuron (or nerve cell) to pass an electrical or chemical signal to another neuron or to the target effector cell (wiki).

1.2 Neuron Membrane Potential

Ions(离子) are molecules or atoms in which the number of electrons (-) does not match the number of protons (+), resulting in a net charge. Many ions float around in your cells. The cell's membrane, a lipid bi-layer, stops most ions from crossing. However, ion channels embedded in the cell membrane can allow ions to pass.



Sodium-Potassium Pump exchanges 3 Na^+ ions inside the cell for 2 K^+ ions outside the cell.

- Causes a higher concentration of Na^+ outside the cell, and higher concentration of K^+ inside the cell.
- It also creates a net positive charge outside, and thus a net negative charge inside the cell.

This difference in charge across the membrane induces a voltage difference, and is called the **membrane potential**.

Neurons have a peculiar behaviour: they can produce a spike of electrical activity called an **action potential** (动作电位). This electrical burst travels along the neuron's *axon* to its *synapses*, where it passes signals to other neurons.

1.3 Hodgkin-Huxley Model

Alan Lloyd Hodgkin and Andrew Fielding Huxley received the Nobel Prize in Physiology or Medicine in 1963 for their model of an action potential (spike). Their model is based on the nonlinear interaction between membrane potential (voltage) and the opening and closing of Na^+ and K^+ ion channels.

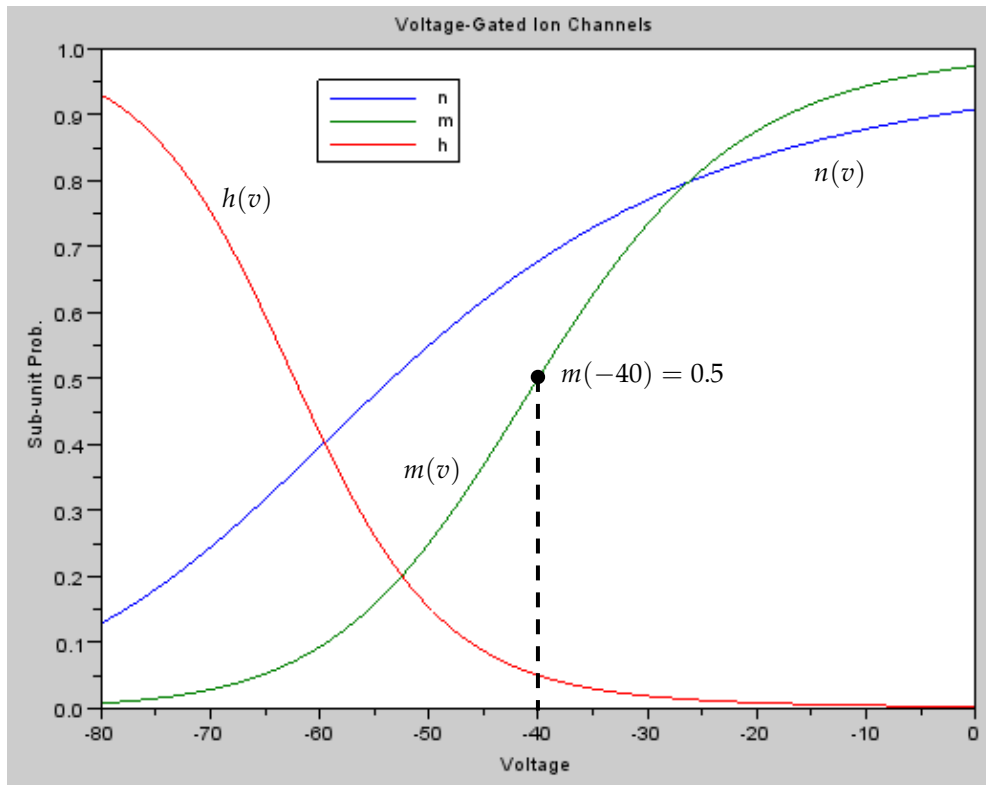
Both Na^+ and K^+ ion channels are voltage-dependent, so their opening and closing changes with the membrane potential.

Let V be the membrane potential. A neuron usually keeps a membrane potential of around -70mV .

The fraction of K^+ channels that are open is $n(t)^4$, where $\frac{dn}{dt} = \frac{1}{\tau_n(V)}(n_\infty(V) - n)$. Here n is a dynamic variable, and $n_\infty(V)$ is the equilibrium solution constant.

The fraction of Na^+ ion channels is $(m(t))^3 h(t)$, where m and h are each themselves dynamic variables that also depend on the voltage.

$$\begin{aligned}\frac{dm}{dt} &= \frac{1}{\tau_m(V)}(m_\infty(V) - m) \\ \frac{dh}{dt} &= \frac{1}{\tau_h(V)}(h_\infty(V) - h)\end{aligned}$$



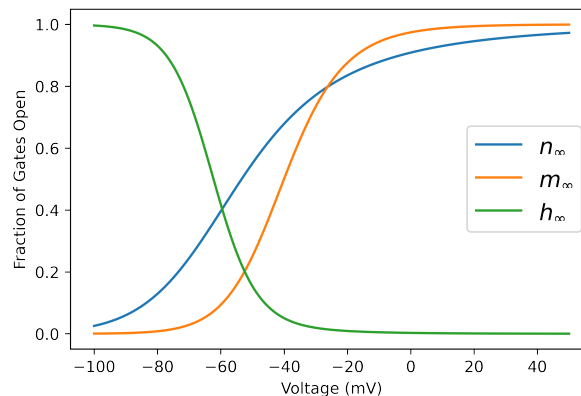
These two channels allow ions to flow into/out of the cell, inducing a current... which affects the membrane potential, V . Here is a differential equation which governs the membrane potential.

$$C \frac{dV}{dt} = J_{in} - \underbrace{g_L(V - V_L)}_{\text{leak current}} - \underbrace{g_{Na}m^3h(V - V_{Na})}_{\text{sodium current}} - \underbrace{g_Kn^3(V - V_K)}_{\text{potassium current}}$$

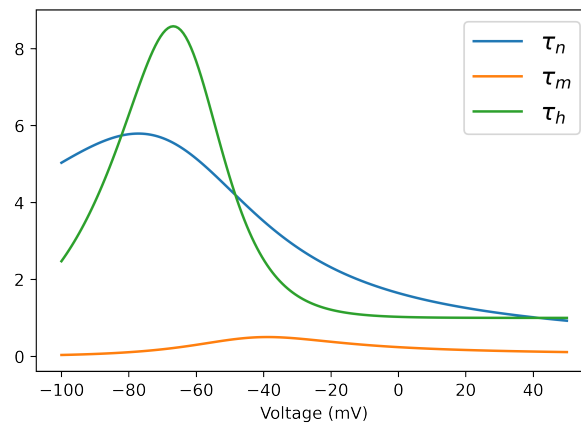
- C : capacitance.
- $\frac{dV}{dt}$: rate of change in voltage, or current.
- J_{in} : input current, usually from other neurons.
- V_L, V_{Na}, V_K : zero-current potentials.
- g_L, g_{Na}, g_K : max conductance.

This system of four differential equations (DEs) governs the dynamics of the membrane potential. Notice what happens when the input current is: negative, zero, slightly positive, very positive.

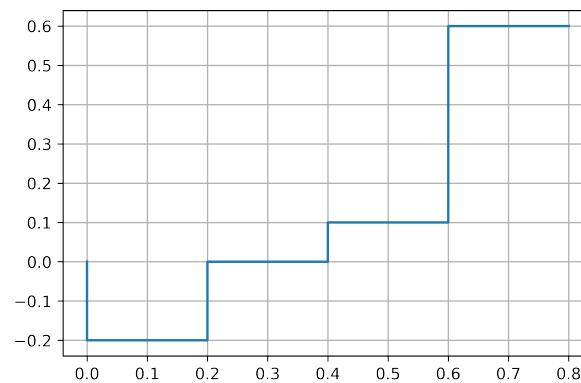
Here we can model this model in python. We have already seen these as functions of voltage.



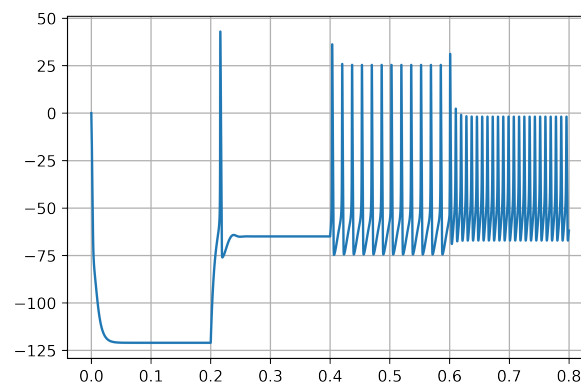
These are the τ 's in case you are interested.



Here is the input current. At the beginning, we have negative current, then way to 0.6, which is fed in to the model.



Then this is how neuron behaves.



At the beginning, membrane potential goes to around -120 . As we increase the input current, the membrane potential kinda goes higher. At 0.1, it's high enough that causes regular action potentials. As we increase input current even more, the action potentials continue to occur even faster. The firing rate of neurons goes up, the number of spikes per second goes up.

The HH model is already greatly simplified:

- a neuron is treated as a point in space
- conductances are approximated with formulas
- only considers K^+ , Na^+ and generic leak currents

- etc.

But to model a single action potential (spike) takes many time steps of this 4-D system. However, spikes are fairly generic, and it is thought that the *presence* of a spike is more important than its specific shape. So instead of modelling spikes themselves, we are going to offload that to some generic spike phenomenon and look at the sub-threshold membrane potential model that.

1.4 Leaky Integrate-and-Fire Model

The leaky integrate-and-fire (LIF) model only considers the sub-threshold membrane potential (voltage), but does NOT model the spike itself. Instead, it simply records when a spike occurs (i.e., when the voltage reached the threshold). So here is the model.

$$C \frac{dV}{dt} = J_{in} - g_L(V - V_L)$$

- C : capacitance.
- g_L : conductance and $g_L = \frac{1}{R}$ where R is resistance.
- J_{in} : input current.

If we multiply both sides by R , we get

$$\underbrace{RC}_{\tau_m} \frac{dV}{dt} = RJ_{in} - (V - V_L).$$

- τ_m : time constant which dictates how quick things happen.
- RJ_{in} : by Ohm's Law, let $V_{in} = RJ_{in}$.

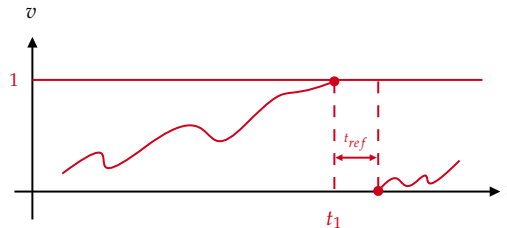
Thus, the voltage can be modelled as

$$\tau_m \frac{dV}{dt} = V_{in} - (V - V_L) \quad \text{for } V < V_{th}.$$

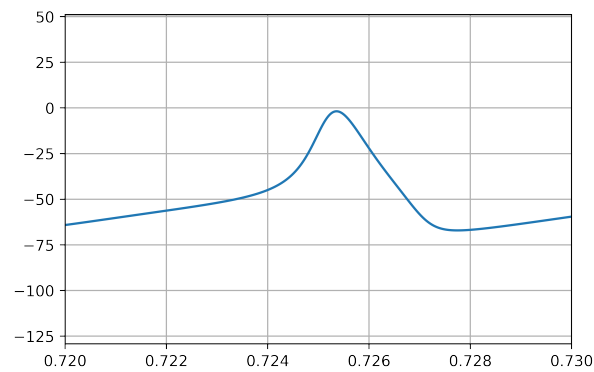
So this is the dynamics of the sub-threshold membrane potential. Change of variables: $v = \frac{V - V_L}{V_{th} - V_L}$, then $v \rightarrow 0$ if $v_{in} = 0$ and $v = 1$ is the threshold. Then we end up with a DE:

$$\tau_m \frac{dv}{dt} = v_{in} - v.$$

We integrate the DE for a given input current (or voltage) until v reaches the threshold value of 1. Then we record a spike at time t_1 . After it spikes, we wait a little bit, τ_{ref} , refractory time. It remains dormant during its refractory period, τ_{ref} (often just a few milliseconds). After that time, we integrate again from zero.



Let's put this in the context of the Hodgkin-Huxley model. If we zoom in on some little spikes here (between 0.72, 0.73). We can see as follows:



So the Hodgkin-Huxley model does model the spike itself.

LIF Firing Rate

Suppose we hold the input, v_{in} , constant. We can solve the DE analytically between spikes.

Claim

$v(t) = v_{in}(1 - e^{-\frac{t}{\tau}})$ is a solution of the IVP: $\tau \frac{dv}{dt} = v_{in} - v$, $v(0) = 0$.

Proof:

Plug in the solution to the DE and show LHS = RHS.

□

What does the solution look like?